

Filed

PATENT Atty. Docket: 10191/1466

APR 1 5 2002

## <u>IN THE UNITED STATES PATENT AND TRADEMARK OFFICE</u>

Applicant : Volker BECKER, et al.

Serial No. : 09/581,663

August 3, 2000

For : METHOD FOR PROCESSING SILIC

BY ETCHING PROCESSES

Group Art Unit : 1746

Examiner : S. AHMED

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Workington, D.C. 2002, on

Assistant Commissioner Washington, D.C. 20231 on

for Patents Washington D.C. 20231 Date: 3/2 7 , 2002 Reg. No. 36,197
Signature: 16mg H. Lee

## AMENDMENT

Sir:

In response to the Office Action mailed December 21, 2001, the Applicants respectfully submit the following amendments and remarks. The Applicants respectfully request a one-month Extension of Time to respond to the Office Action. The extended period expires on April 22, 2002, due to the one-month extended due date falling on a Sunday.

04/55/5005 WEINETEL 0000000 Troco IN 03201009

588.00 CH 125.00 CH Please cancel

185.00 CH Please cancel claims 1-31, without prejudice to the subject matter therein.

Please add the following new claims 32-69:

32. (New) A method for etching a silicon layered body, which has a first silicon layer (15) that is provided with an etching mask (10) for defining lateral recesses (21);

1/20/1